Contents lists available at ScienceDirect



Materials Characterization

journal homepage: www.elsevier.com/locate/matchar

# A study approach on ferroelectric domains in BaTiO<sub>3</sub>

L.S.R. Rocha<sup>a</sup>, C.S. Cavalcanti<sup>a</sup>, R.A.C. Amoresi<sup>b,\*</sup>, B.D. Stojanovic<sup>c</sup>, E. Borsari<sup>a</sup>, M.A. Za

<sup>a</sup> Faculty of Engineering of Guaratinguetá, São Paulo State University - UNESP, Guaratinguetá, SP, Brazil

<sup>b</sup> Interdisciplinary Laboratory of Electrochemistry and Ceramics, LIEC – Department of Chemistry Techonology, Chemistry Institute, São Paul

<sup>c</sup> Institute for Multidisciplinary Research, University of Belgrade, Kneza Viselava 1, 11000 Belgrade, Serbia

Simões <sup>a</sup> - UNESP, A

quara, SP, Brazil

te⊳,

tate Ur

CrossMark

MATERI/

#### ARTICLE INFO

Article history: Received 6 April 2016 Received in revised form 5 September 2016 Accepted 10 September 2016 Available online 12 September 2016

Keywords: Ceramics Crystal growth Piezoelectricity

#### 1. Introduction

Barium titanate (BaTiO<sub>3</sub>) has been extensively in sev industrial applications, including dynamic rap memo 1 ac (DRAM) capacitor, microwave filters, infrare l dielectr *c*ectors phase shifters, owing largely to their excellen <mark>ہ</mark>]. Fo piezoelectric and pyroelectric properties BO3 perovskite, different A-site and B-site dopants (w A = Ca, Sr,= Nb, Ta, Zr) GiO3 based are used aiming at modifying the properties compositions [1-9].

As widely acknowledge based piezo materials ides and nit are used in electronic d applications inc ng MEMS, FeRAMs erostr and other ferroelectri res [10–11]. An understanding of local ferroelectric pro as strong coupling between electrical and mechanical respons e nanop level will undoubtedly ends. Scanning probe techniques hance the fu ty of 1 ma oloyed at gaining understanding of the are, by ar rge, local fe ectric b avior on such length scales. Atomic Force Acoustic AL response Force Microscopy (PFM) are Microso relevant Scanning Probe Microscope (SPM)-based among the techniques wh re capable of evaluating ferroelectric properties on nanoscale [12–1] ese techniques allow the imaging of ferroelectric domains architecture at ~10 nm level while providing direct information on localized electromechanical activity. Chen et al. have studied the research progress on ferroelectric domains of lead-free films with relatively good ferroelectric and piezoelectric response which have been attributed to the films well-defined domain structure [19]. In a

Corresponding author. E-mail address: rafaelciola@yahoo.com.br (R.A.C. Amoresi).

#### ABSTRACT

Atomic Force Acoustic Microscopy (AFAM) and (PFM) were used to study local esponse Fo ati-mode Scanning Probe Microscoelastic and electromechanical response in BaT cs. A comme py (SPM) and AFAM mode to image contact employed accomplish the aforementioned purffne poses. Stiffness parameters along with Young's moduli ezo coefficients were quantitatively determined. PFM studies were based on electrost lectromechai sponse from localized tip-surface contact. Comg s moduli obtained by parison was made regarding the AM and PFM. In addition, phase and amplitude ng behavior, obtained via the application of -10 V to +10 V local voltage. images were analyzed based on © 2016 Elsevier Inc. All rights reserved.

> work, the authors were able to improve the magnetic coupling of BixeO<sub>3</sub>/Bi<sub>4</sub>Ti<sub>3</sub>O<sub>12</sub> composite obtained by a chemical solution deposition with desirable ferroelectric, piezoelectric and dielectric responses as well as low leakage current, paving the way towards its future application in sensors and spin devices. These results are essentially associated with a strong coupling between ferroelectric and ferromagnetic orders as a result of the coexistence of different domain structures of this composite [20].

> Based on these facts, we will conduct a systematic study approach of a lead-free bulk system composed of BaTiO<sub>3</sub> (BT), which is a ferroelectric material found to exhibit excellent piezoelectric behavior, resulting in wide applications in electronic control systems. BT possesses high dielectric constant and, generally, good ferroelectric properties. The study of ferroelectric domain behavior is seen to be of vital significance in view of the current upsurge of interest in multiferroic materials [3–8]. To achieve the desired properties, BT primarily needs to be free of intermediate crystalline phases, with a defined stoichiometry and a homogeneous microstructure. It is noteworthy that a wide range of preparation methods for BT have been investigated. The solid state reaction, starting from BaCO<sub>3</sub> or BaO, and TiO<sub>2</sub>, has been shown to be suitable for the preparation of BT ceramics with high performance application as the resulting material exhibits large particle size and grain growth [21]. The main constraint of the solid state reaction lies in the fact that it requires repeated heat treatments besides grinding and contamination often becomes a problem [22]. This paper presents the results of the studies conducted using Atomic Force Acoustic Microscopy (AFAM) and Piezo Force Microscopy (PFM) to monitor the organization of local ferroelectric domains in BaTiO<sub>3</sub> ceramic pellets prepared by solid state reaction with careful control of impurities. In addition, electromechanical coupling related to elastic and piezo properties of the material were also thoroughly assessed. Elastic constant and piezo coefficient were



Fig. 1. XRD pattern of the BaTiO<sub>3</sub> pellet prepared via solid state reaction.

calculated. AFAM and PFM responses were investigated at various zones of the barium titanate pellets. Furthermore, a point-by-point mapping of piezospectroscopic behavior was carried out [23,24].

#### 2. Experimental Procedure

 $BaTiO_3$  (BTO) samples were synthesized by solid state reaction. The barium titanate was prepared starting from barium oxide (BaO) and

titanium oxide (TiO<sub>2</sub>), in a rutile crystal form (Fluka, 99.8% purity). BaO was obtained from BaCO<sub>3</sub> (E. Merck, 99.0% purity) according to the following reaction:  $BaCO_3 \rightarrow BaO + CO_2$  in air at 900 °C/4 h. After polishing, AFM studies using different modes were carried out through SPM with Nanoscope IV controller equipped with standard silicon nitride tips coated with gold-cadmium. The typical force constant of these tips was 0.09 N/m and the apex radius was 20-40 nm. The AFM methodology, which is useful for obtaining local elasticity images, has been previously discussed in the literature [9,25,26]. This principle was optimized so as to evaluate local mechanical properties of the BaTiO<sub>3</sub> pellet. AFM measurements were carried out in contact mode. A conducting AFM tip was used to apply an A tage superimposed with a DC bias for computing piezo activit variation in the direction of domain orientation is achieved g the magnia by contr tude of impressed voltage [9–11,27,28 spectrosco was carried out for the bias voltage within the 0 V to -V aiming at nge studying piezoresponse and p action exi erent regions. stigated by PFM The piezoresponse from fer ctric p erials v voltage was a combination of a with a resolution of 10 n e api at result DC bias and an altern n cantilever deflection. ng v The PFM image w cy of ~790 kHz. tained a t free

tion of the sp The acoustic was maintained at 2.25 MHz. . th In order to nplete rang of the flexural vibrations of the cantilever, the emplo frequency was changed from 10 kHz to nplitude and 2 MHz ency shifts resulting from coupled oscilwere recorded follow lati g mapping. Similarly, stiffness constants w derived from force-distance curves. Contact resonance frequency ies on BaTiO<sub>3</sub> pellet were recorded. This method сυ in AFAM



Fig. 2. Comparison between topography (a) and resonance frequency image (b) of the BaTiO<sub>3</sub> pellet surface.

has been described earlier [3–9]. For the sake of clarity, the following mathematical expression was used:

$$k_{BaTiO_{3}}^{*} = k_{Si}^{*} \frac{\left[f_{BaTiO_{3}}^{2} - f_{Si}^{2}\right]}{\left[f_{Si}^{2} - f_{0}^{2}\right]}$$
(1)

where

 $k^*_{BaTiO3}$ : contact stiffness of the sample pellet,

k\*si: contact stiffness of the Silicon wafer (used as reference),

f<sup>\*</sup><sub>BaTiO3</sub>: contact resonance frequency of the sample pellet,

f<sup>\*</sup><sub>Si</sub>: contact resonance frequency of the Si wafer and,

f<sub>0</sub>: free resonance frequency of the cantilever.

These calculations were made after recording resonance spectra.

#### 3. Results and Discussion

Fig. 1 shows the XRD patterns for the BaTiO<sub>3</sub> pellet prepared via solid state reaction. The Bragg peaks indicate the crystallization of BT perovskite phase with *P4mm* space in the crystalline tetragonal structure (JCPDS card no. 05-0626). It is worth noting that no secondary or intermediate carbonate phases were observed. The absence of BaCO<sub>3</sub> can be attributed to complete reaction. Perovskite BaTiO<sub>3</sub> phase was seen to be well-crystallized implying the occurrence of the solid state reaction while the nucleation and subsequent growth of perovskite crystallites were found to be favored at 900  $^{\circ}$ C/4 h.

Fig. 2a-b illustrates the topography and acoustic mode in resonance frequency acquired simultaneously. Topography image (Fig. 22) was mapped in AFM contact mode, where large grains in the form umns are observed devoid of pores. In Fig. 2b, the acoustic im ables the visualization of the grains substructures. The selected of the excitation frequency was 2.25 MHz which is a the co resonance (10 kHz-2 MHz). Thus, stiffer regions · brigh The acoustic images are formed by a columns pa 1 with ite strip parallel along the dark stripes, typical of polar n 180° the crystal [29,30]. Fig. 2c is an enlarged a of grain boundaries and white stripes for s characteristic by smah These substru of substructures marked in dashed s are stiffer ntours composed of ferrostructures formed by nanograins 4 th electric domains along them Quantitativ lysis of the stiffness in those zones was carried sing reference ples such as Si and PZT. Furthermore, the I image depicts regular and irregular "fingerprint-like" doma ttern arious zones on the pellet surface. The large zones with sa ain in t<sup>k</sup> image are actually consisted elow 50 of smaller dom ructu . Guided by the aim of studying the beh se don r electric field, PFM studies were witching and are described in the perform oservi the dom. next st ction

Fig. 3 cture of the pellet in different regions showing the ndence of the deflection with distance. The obtained curves clearly s distinct inclinations, as the pink curve deflection decreases continuesly even after the detachment from the center (zero), while the green curve remains constant during extension and retraction of the tip. Such behavior is a reflection of heterogeneity in several regions caused by different surface rigidity. Using reference samples, stiffness constants for several coupled systems were quantitatively determined, and are given in Table 1. Contact resonance spectra from few representative points on BaTiO<sub>3</sub> surface are shown in Fig. 3b. The mechanical spectrum is influenced by the elastic and viscous behavior of the sample once the tip stiffness is constant. Significant changes in frequency and magnitude of the contact resonance ranging from 1290 kHz to 1337 kHz between the various locations can be clearly noted. The larger vibrational frequency of the spectra implies a decrease in its vibrational wavelength of interaction caused by stiffer region of



Fig. 3. a) Force curves and b) contact resonance frequencies for various points on the surface of  $BaTiO_3$  pellet.

the sample. The amplitude, which is related to the energy dissipation of the interaction, must be evaluated by the full width at half maximum (FWHM) of the peaks, where softer regions exhibit broader peaks followed by a reduction in amplitude. The shape of the peak in doublet can be represented by two springs in series representing elastic behavior among the cantilever-sample interactions [31]. Stiffness constants as well as resonance peak shifts are used in the evaluation of Young's modulus (E) [6–9] according to Eqs. (2) and (3):

$$E_{BaTiO_{3}}^{*} = E_{Si}^{*} \left( \frac{k_{BaTiO_{3}}^{*}}{k_{Si}^{*}} \right)^{3/2}$$
(2)

$$\frac{1}{E^*} = \frac{1 - \nu_{tip}^2}{E_{tip}} + \frac{1 - \nu_{BaTiO_3}^2}{E_{BaTiO_3}}$$
(3)

Estimated moduli evaluated using these formulations, are given in Table 2.

able 1			
alues of effective stiffness and	elastic constants for	or sample and referen	nce materials.

Coupled system	F (nN)	$\mathrm{K^{*}}\left(\mathrm{N/m}\right)\pm10\%$	${\rm E^*}~(\times 10^{10}~{\rm N/m^2})\pm 10\%$
Si-W <sub>2</sub> C	250	11.3	5.6
PZT-W <sub>2</sub> C	300	10.5	4.2
BTO-W <sub>2</sub> C	300	22.3	14.4

# Table 2

Elastic modulus and	Poisson's	coefficients	for	various	materials
Liasue moutinus and	1 0133011 3	COCINCICICICS	101	various	matchans

Materials	E ( $\times 10^{10}$ N/m <sup>2</sup> ) reported	ν	$E~(\times 10^{10}~\text{N}/\text{m}^2)$
Si	11.8	0.28	10.3
PZT	10.2	0.29	6.2
BaTiO <sub>3</sub>	13.7	0.27	16.5

To improve contrast in the AFAM image, and to enable investigation of finer features, the image was mapped at two different frequencies, below (Fig. 4a) and above (Fig. 4b) the resonance frequency. In Fig. 4a, the mapping below resonance frequency clearly shows bright and dark regions, where bright regions indicate soft zones while dark ones correspond to hard zones. Similarly, AFAM image was mapped at a freguency above resonance value, which is shown in Fig. 4b, where the hard and soft zones found here point to contrast inversion, through which the axis of orientation measured in the unit cell is dependent on the tip probe. Through the dotted arrows, in Fig. 4a and Fig. 4b, one can clearly observe the presence of substructures, having different contrasts according to the applied resonance contrast indicating variation in contact stiffness [7–9]. Domains with average size of ~50 nm bearing different values of stiffness are clearly visible. Fig. 4c shows topography while poling. The corresponding piezoresponse image (using magnitude signal mapping, in the PFM mode), obtained by adjusting various DC bias voltages, ranging from -10 V to +10 V for different times, is given in Fig. 4d. The image indicates that the perpendicular component of polarization can be switched between two stable states: bright and dark. The piezoelectric response component in the out of plane direction is represented by a line profile during poling, as shown in Fig. 4e, which is a reference of the lines depicted in Fig. 4c-d. Such behave in effect, corresponds to the different orientations of polarized mains. Dark regions with higher current correspond to domains or ed in the same direction of the polarization axis (soft domains), w bright regions are related to domains perpendicular to the larizati axis, which explains their reason of having low (har domains).

For a much thorough comprehension of the system, the piezoelectric vibrations were monitored through of the observation of the amplitude, which is connected to the piezoelectric coefficient of the material. Similarly, the phase of the signal is capable of revealing the polarization direction. Fig. 5a shows PFM images along with topography, with area ~  $10 \times 10 \,\mu\text{m}^2$ , for different regimes present in the area. The amplitude of the piezoelectric vibration is shown in Fig. 5b, the bright area illustrates the piezoelectrically active region parallel to the applied electric field while dark regions are associated with piezoelectrical activities oriented in the opposite direction of the applied field on the pellet surface. Phase image (Fig. 5c) clearly shows the polarization direction in different zones at various voltage nd the topmost and bottommost areas in the image have the The observed piezo domains are attributed to the se piezoric effect on the material surface. Applied voltage is electromevn to cause ng beha chanical realignment of the dom s Th was monitored by locally applying vol 0 V +10 V [13betweet une of approxi-14]. Corresponding to thes itages anges the e- and amputude-contrast immately 40% were observ its, piez ages. In these images ectroscopy was carried vai out.

In order to ve quantita dysis of the PFM data, the electroelasti â bution was ained. By meticulous observation, it was found that teresis loop could be obtained using a stiff points on t rface. Fig. 6 shows the piezo response tip at appraude and phase statisticals as a function of bias voltage at a typusi ic oint. Fig. 6a shows the typical piezoresponse amplitude of the pelle mediately le applying -10 V to +10 V DC biases over the region b he AFM tip, along the direction perpendicular to sca e maximum piezoresponse signal seen in the butterthe in ...ed left by 0.3 V. This may be associated with different fly loop is functions existing between the two electrodes, i.e. the tip and I plate. Above 6 V, the value of piezoresponse is found to be most flat. Apart from the magnitude, the sign of the piezo response, which is related to the polarization direction of a zone point on the surface, is seen to undergo a change. Fig. 6b shows the piezoresponse phase



**Fig. 4.** AFAM images below (a) and above (b) the resonance frequency. AFAM image while/during poling (c). Piezoresponse (magnitude signal mapping) image (d) while poling using various DC bias voltages ranging from -10 V to +10 V at different durations and line profile during poling (e).



Fig. 5. Topography during poling (a), PFM amplitude (b) and PFM phase (c) images during poling while applying different DC bias, with volu

10 V to + 10 V.

as a function of the applied DC voltage. It reveals the phase difference of the detected signal existing between positive and negative voltages. By combining the amplitude loop (i.e. butterfly loop and phase loop), one can obtain the hysteresis loop. Fig. 6c illustrates the piezoelectric hysteresis loop response of the BaTiO<sub>3</sub>. Characteristic loop is known to be dependent mainly on the properties of the pellet. The comparative inferences and observations of AFAM and PFM are discussed below.

Based on the AFAM studies at various resonance frequencies, the images are clearly noted to be very informative regarding the grains, grain boundaries and domain architecture. A wide range of domains shapes and sizes are clearly seen. Stiffness variation over the surface is about <12%, which may be attributed to the grain, grain boundaries and domains. In addition, microscopically, this variation of stiffness can arise from pellet parameters such as surface roughness. A further observation worth mentioning is that the BTO pellet surface is found to be harder compared to those of Si and PZT (Table 2). Variation in E may stem from different zones having varying elasticities. Distribution of (between 14 and  $18 \times 10^{10}$  N/m<sup>2</sup>) in the polished pellet is seen to in fluenced by their morphology. In PFM, the total force acting on th М tip is a combination of two forces. One of these forces elastic exerted by the cantilever with a constant spring k tion po  $d_0$ . The other force denoted as  $F_{el}$  is the electrop force the latt rimpo force is modulated by a sinusoidal voltage component, cantilever response varies ac din lated to electrical and mechanical-(el of the surface. ) prope surface elect Hence, cantilever response, based chanical interaction, changes with bias vol orted in the erature [3– 7], an approximate value of riezocoefficie calculated to be about  $\sim 9 \times 10^{-11}$  m/V, which is ost 50% of that e PZT pellet. Elastic  $(m^2)$  v constant (E ~  $14.3 \times 10^{-1}$ s estimated a relation derived by Kalinin and rapetian [32] which employed piezocoefficient and Yo uli for p crystalline materials within



Fig. 6. Piezoresponse at a typical point on the pellet surface.

the electromechanical regime, bring t with the surtip into co face, generating a first-harmon of bias-i ced tip deflecrompo information on tion  $d = d_0 + A \cos(\omega t + \omega)$ th the pha viel ains with polarizathe polarization direction ow the o. For c vard application of a positive bias tip tion vector pointing d causes surface osc xpansio the sample, as such the tio thus voltage = 0. And for c<sup>+</sup> domains phase with the ctor pointing with polariza  $q, \phi = 180^{\circ}$  [22]. The amplitude .00 A defines tromechank response and depends on the geometry of the tip-s e junction and materials properties, whose cal descript mat re deemed extremely complex to ascertain. parison was made be veen E values obtained by AFM and PFM. ther improvements in these studies ought to be done through the ancement ellet density, morphology and electrical contacts. uther stu s, our intention is to have a metallic electrode film e pellet and/or a film to reduce the working function on intact problems. as web

# 4. Conclusions

To aid our understanding of the nanoscale behavior of piezo domains in  $BaTiO_3$  ferroelectric materials, AFAM and PFM studies were successfully executed. In AFM, height images give us a hint regarding the roughness variation along with topography for the test and reference samples. Topography and AFAM images clearly indicate the stiffness variation on nanoscale in substructures within the grains. Below 50 nm, ferroelectric domains with different values of stiffness were clearly observed in the AFAM image of the pellet. Quantifications of stiffness and elastic constants were carried out using standard reference samples such as Silicon and PZT. The spatial inhomogeneity of ferroelectric domain structure reveals that the random internal field observed is attributed to the nanoscale structural irregularities on the material. Under PFM mode, piezoresponse of domains with respect to the applied electric field was investigated. Electromechanical realignment of the domains was observed during poling.

## Acknowledgements

The authors would like to express their warm gratitude to Dr. Ramesh for his useful discussions on AFAM and PFM at various stages of the research. The authors do acknowledge the sustained encouragement and financial support provided by CNPq (573636/2008-7), INCTMN (2008/57872-1) and FAPESP (2013/07296-2) research funding agencies. Our thanks also go to Brian Newmann – the English language content editor for his painstaking editing and proofreading of the manuscript.

### References

 H.Y. Tian, Y. Wang, J. Miao, H.L.W. Chan, C.L. Choy, Preparation and characterization of hafnium doped barium titanate ceramics, J. Alloys Compd. 431 (2007) 197–202.

[3

- [2] J.Y. Chen, Y.W. Tseng, C.L. Huang, Improved high Q value of (1 x)Ca(Mg1/3Ta2/ 3)O3-xCa0·8Sm0.4/3TiO3 solid solution with zero temperature coefficient of resonant frequency, J. Alloys Compd. 494 (2010) 205–209.
- [3] F. Boujelben, F. Bahri, C. Boudaya, A. Maalej, H. Khemakhem, A. Simon, M. Maglione, Effect of Ni doped BaTiO3 on the dielectric properties in the Ba(Ni1/3Nb2/ 3)xTi1 – xO3 solid solution, J. Alloys Compd. 481 (2009) 559–562.
- [4] Q. Xu, X.F. Zhang, Y.H. Huang, W. Chen, H.X. Liu, M. Chen, B.H. Kim, Effect of MgO on structure and nonlinear dielectric properties of Ba0 6Sr0.4TiO3/MgO composite ceramics prepared from superfine powders, J. Alloys Compd. 488 (2009) 448–453.
- [5] O.P. Thakur, P. Chandra, A.R. James, Enhanced dielectric properties in modified barium titanate ceramics through improved processing, J. Alloys Compd. 470 (2009) 548–551.
- [6] H.I. Hsiang, C.S. Hsi, C.C. Huang, S.L. Fu, Sintering behavior and dielectric properties of BaTiO3 ceramics with glass addition for internal capacitor of LTCC, J. Alloys Compd. 459 (2008) 307–310.
- [7] Z.G. Hu, Y.W. Li, M. Zhu, Z.Q. Zhu, J.H. Chu, Microstructural and optical investigations of sol-gel derived ferroelectric BaTiO3 nanocrystalline films determined by spectroscopic ellipsometry, Phys. Lett. A 372 (2008) 4521–4526.
- [8] S.F. Wang, Y.R. Wang, Y.C. Wu, Y.J. Liu, Densification, microstructural evolution, and dielectric properties of hexagonal Ba(Ti1 – xMnx)O3 ceramics sintered with fluxes, J. Alloys Compd. 480 (2009) 449–504.
- [9] M. Cernea, E. Andronescu, R. Radu, F. Fochi, C. Galassi, Sol-gel synthesis and characterization of BaTiO3-doped (Bi0·5Na0.5)TiO3 piezoelectric ceramics, J. Alloys Compd. 490 (2010) 690–694.
- [10] A. Gruverman, O. Auciello, H. Tokumoto, Imaging and control of domain structures in ferroelectric thin films via scanning force microscopy, Annu. Rev. Mater. Sci. 28 (1998) 101–123.
- [11] A. Moulson, H. JM, Electroceramics: Materials, Properties, Applications, Chapman and Hall, London, 1990.
- [12] E. Kester, U. Rabe, L. Presmanes, P. Tailhades, W. Arnold, Measurement of Young's modulus of nanocrystalline ferrites with spinel structures by atomic force acoustic microscopy, J. Phys. Chem. Solids 61 (2000) 1275–1284.
- [13] S.V. Kalinin, D.A. Bonnel, Imaging mechanism of piezoresponse force microscopy of ferroelectric surfaces, Phys. Rev. B 65 (2002) (125408-1-11).
- [14] T. Stoica, R. Calacro, R. Meijers, H. Lüth, Nanoscale imaging of surface piezoresponse of GaN epitaxial layers, Appl. Surf. Sci. 253 (2007) 4300–4306.
- [15] S.V. Kalinin, D.A. Bonnell, Atomic polarization and local reactivity on ferroelectric surfaces: a new route toward complex nanostructures, Nano Lett. 2 (2002) 589–593.
- [16] U. Rabe, V. Scherer, S. Hirsekorn, W. Arnold, Nanomechanical surface charaction by atomic force acoustic microscopy, J. Vac. Sci. Technol. B 15 1506–1511.

- [17] U. Rabe, S. Amelio, E. Kester, V. Scherer, S. Hirsekorn, W. Arnold, Quantitative determination of contact stiffness using atomic force acoustic microscopy, Ultrasonics 38 (2000) 430–437.
- [18] M. Prasad, M. Kopycinska, U. Rabe, W. Arnold, Measurement of Young's modulus of clay minerals using atomic force acoustic microscopy, Geophys. Res. Lett. 29 (2002) 13-1-13-4.
- [19] J. Chen, Z. Tang, R. Tian, Y. Bai, S. Zhao, H. Zhang, Domain switching contribution to the ferroelectric, fatigue and piezoelectric properties of lead-free Bi0.5(Na0.85 K0.15)0.5TiO3 films, RSC Adv. 6 (2016) 33834.
- [20] J. Chen, Z. Tang, Y. Bai, S. Zhao, Multiferroic and magnetoelectric properties of BiFeO3/Bi4Ti3O12 bilayer composite films, J. Alloys Compd. 675 (2016) 257–265.
- [21] P. Guthner, K. Dransfeld, Local poling of ferroelectric polymers by scanning force microscopy, Appl. Phys. Lett. 61 (1992) 1137–1139.
- [22] S.V. Kalinin, E. Karapetian, M. Kachanov, Nanoelectromechanics of piezoresponse force microscopy, Phys. Rev. B 70 (2004) (184101-1-24).
- [23] Q.X. Jia, H.H. Kung, X.D. Wu, Microstructure property of 5,55r0.5TiO3 thin films on Si with conductive SrRuO3 bottom electron and Films 299 (1997) 115–118.
- [24] B.L. Newalkar, S. Komarneni, Microwave the thermal synthesis of characterization of barium titanate powders, Mater. Res. 26 (2001) 234 355.
- [25] G. Mangamma, B. Ramachandran, T. Asiram, A. Barnen, and S. Dash, A.K. Tyagi, Imaging of nanometric ferroctric domasing BaTiCoung atomic force acoustic microscopy and piece ace microscopy, J. 2010, osc. Res. 6 (2011) 29–34.
- [26] T. Stoica, R. Calarco, R. Messer, Luther oscale imaging of surface piezoresponse on GaN epitaxial layer Appl. 23 (2007) 20–4306.
- [27] L.M. Eng, H.J. Günther, G.A. S. Her, U. Körn, J.M. Saldaña, Nanoscale reconstruction of surface systallograph. the mensional polarization distribution in ferroel visual-titanate complexity. Phys. Lett. 74 (1999) 233–235.
- [28] K. Yamano and Name Quantitative encloty evaluation by contact resonance in an atomic to ce micro. Appl. Phys. A Mater. Sci. Process. 66 (1998) S313–S317.
  [29] V. Grubsky, S. MacCorna, Feinberg, All-optical three-dimensional mapping of 12 micro. In hidden in a concrystal, Opt. Lett. 21 (1996) 6–8.
- [30] Looms, N.T. Tsou, J.E. Huber, review of domain modelling and domain imaging chniques in ferroglectric crystals, Materials 4 (2011) 417–447.
  - Collins, A. Tseiner, J. Jesse, M.B. Okatan, R. Proksch, J.P. Mathews, G.D. Mitchell, B.J. driguez, S.V. konn, I.N. Ivanov, Breaking the limits of structural and mechanical ting of the horizon structure of coal macerals, Nanotechnology 25 (2014)
- [32] E. N. S. Kachanov, S.V. Kalinin, Nanoelectromechanics of piezoelectric indentation and applications to scanning probe microscopy of ferroelectric materials, pilos, Mag. 85 (2005) 1017–1051.